NSN 5961-01-216-7265

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Inclosure Material:

Plastic

Overall Length:

0.650 inches

Overall Height:

0.190 inches

Overall Width:

0.420 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-60.0 collector to base voltage/static/emitter open and -60.0 collector to emitter voltage/static/base open and -7.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

-3.00 amperes source cutoff current and -0.50 amperes source cutoff current

Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector

Transfer Ratio:

200.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: nip

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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